

High Power GaN Amplifier at 5 Watt Psat Operating from 2 GHz to 18 GHz with SMA

The FMAM5068 is a high power amplifier that operates from 2 GHz to 18 GHz and generates 5 watts of saturated output power. The module utilizes GaN and chip-and-wire technology in the manufacturing process that ensures state-of-the-art power performance with excellent power-to-volume ratio that's ideal for broadband high power linear applications. This Class AB amplifier is designed for a 50 ohm input/output impedance and offers high efficiency and high linearity, operating over a wide dynamic range with impressive typical performance that includes 37 dB gain, ± 2 dB gain flatness, -12 dBc 2nd harmonic suppression, -55 dBc Spurious, and a maximum input power level of +10 dBm. Typical DC bias requirements include +28V and 2A of current. The module uses an SMA female input and output connector. The DC interface incorporates a D-Sub 9 pin male connector for DC bias, Enable with TTL logic control, Current Sense, and Temperature Sense functions. A mating female D-SUB socket connector is included. The rugged amplifier design operates over wide temperature range from -25°C and +60°C and can withstand relative humidity exposure up to 95% maximum. An available heatsink with cooling fan (model FMAMG5060F) is recommended to maintain an optimum baseplate temperature during operation.

Electrical Specifications

(TA = +25°C, DC Voltage = +28Volts, DC Current = 2A)

Description	Min	Typ	Max	Unit
Frequency Range	2		18	GHz
Small Signal Gain		37		dB
Gain Flatness		± 2		dB
Psat		+37		dBm
2nd Harmonics @ 2 Watts		-12		dBc
Spurious		-55		dBc
Impedance (Input)		50		Ohms
Impedance (Output)		50		Ohms
Input Return Loss			-10	dB
OFF/ON Switch Time (10% to 90%)		10		μ s
Operating DC Voltage	+26	+28	+30	Volts
Operating DC Current @5 Watts		2		A
Operating Temperature Range	-25		+60	°C

Electrical Specification Notes:

Allow for 20% Increased DC Current during initial power-up stage



Features:

- GaN Design
- 2 GHz to 18 GHz Frequency Range
- Psat 5 Watts typ
- Power Gain: 37 dB typ
- Gain Flatness ± 2 dB typ
- Enable with TTL Logic Control
- Current and Temperature Sense Functions
- 50 Ohms Input and Output Matched
- Broadband and High power
- Unconditionally Stable
- High Efficiency
- Low Distortion
- D-Sub Control Connector with Mating Female Connector
- Optional Heatsink Available: FMAMG5060F

Applications:

- Military Radio
- Communication Systems
- High Gain Driver Power Amplifier
- RF, C, Ku Band Linear Applications
- Test and Measurement applications

Fairview Microwave
 301 Leora Ln., Suite 100
 Lewisville, TX 75056
 Tel: 1-800-715-4396 / (972) 649-6678
 Fax: (972) 649-6689
www.fairviewmicrowave.com
sales@fairviewmicrowave.com

Absolute Maximum Rating

Parameter	Rating
Input RF drive level without damage	+5 dBm (MAX)
Load VSWR @ Pout = 2 W	10:1 @ all load phase & amplitude for duration of 1 minute; 3:1 @ all load phase & amplitude continuous
Over Temperature	85°C @ heatsink [restored @ 60°C]



ESD Sensitive Material,
 Transport material in
 Approved ESD bags. Handle
 only in approved
 ESD Workstation.

Mechanical Specifications
Size

Length 4.72 in [119.89 mm]
 Width 3.15 in [80.01 mm]
 Height 0.87 in [22.1 mm]

Weight 2.64 lbs [1.2 kg]
 Input Connector SMA Female
 Output Connector SMA Female
 Bias Connector 9-Pin D-Subminiature Male

Environmental Specifications
Temperature

Operating Range -25 to +60 deg C
 Storage Range -40 to +65 deg C

Humidity 95% Non-Condensing
 Shock Normal Truck Transport
 Vibration Normal Truck Transport

Compliance Certifications (see [product page](#) for current document)

Plotted and Other Data

Notes:

- Values at 25 °C, sea level
- Heatsink Required for Proper Operation Recommended Model: FMAMG5060F

Amplifier Power-up Precautions

- 1.) Confirm that proper ESD precautions and controls are always in place before handling any Amplifier module.
- 2.) Confirm adequate thermal management is in place to effectively dissipate heat away from the Amplifier package. The Amplifier operational baseplate temperature must be within the operational temperature range stated in the Amplifier datasheet. Depending on the design and thermal requirements, using a heatsink with cooling fan is always recommended for safe reliable operation. A heat sink without a cooling fan may also be used. Damage caused from overheating will void the warranty.
- 3.) Confirm adequate system grounding is established. The DC power supply and Amplifier must have a common ground in order to operate properly.
- 4.) Power Amplifiers may require additional DC Current when initially powered-up. Depending on the design, the input current draw could range from an additional 10% to 100% above the maximum rated DC current of the Amplifier. This varies based on product part number.
- 5.) Confirm the DC power supply, if limited, is set to allow for additional start-up current that's rated for the Power Amplifier.
- 6.) Confirm the system is designed and calibrated for 50 ohms. Any impedance mismatch may cause performance issues.
- 7.) Perform a CALIBRATION (if required) with the loads before connecting the Amplifier to the Network Analyzer to ensure proper performance.
- 8.) Use a fixed attenuator between the signal source and input port of the Amplifier to optimize the input VSWR match.
- 9.) Confirm the input power level at the input port of the amplifier does not exceed the maximum rated limit for input power (as stated in the Amplifier datasheet).
 P_{in} for Small Signal Gain = P1dB-SSG-10 dB
 P_{in} for P1dB = P1dB-SSG+1 dB
- 10.) Confirm the Network Analyzer is always connected to the Amplifier first before DC power is applied to the Amplifier.
- 11.) As long as the input and output ports of the amplifier are connected to a 50Ohm load and RF signal power is applied, the Amplifier can be powered up with DC voltage.
- 12.) Confirm the Amplifier output load is matched for a 50 Ohm impedance and will not exceed the maximum rated VSWR or Return Loss limit for the Amplifier. Exceeding the maximum rated VSWR or Return Loss limit will result in reflected signal power that could damage the Amplifier and void the warranty.
- 13.) **Power Amplifier connected to an Antenna for signal transmission** - It's strongly recommended to use a high power fixed attenuator pad or an Isolator between the output port of the Amplifier and input port to the antenna. Any reflected signal power due to impedance mismatch will likely damage the Amplifier and void the warranty.
- 14.) The attenuator or isolator used at the output port of the Amplifier must be rated to handle the output power level and operational frequency band of the amplifier.

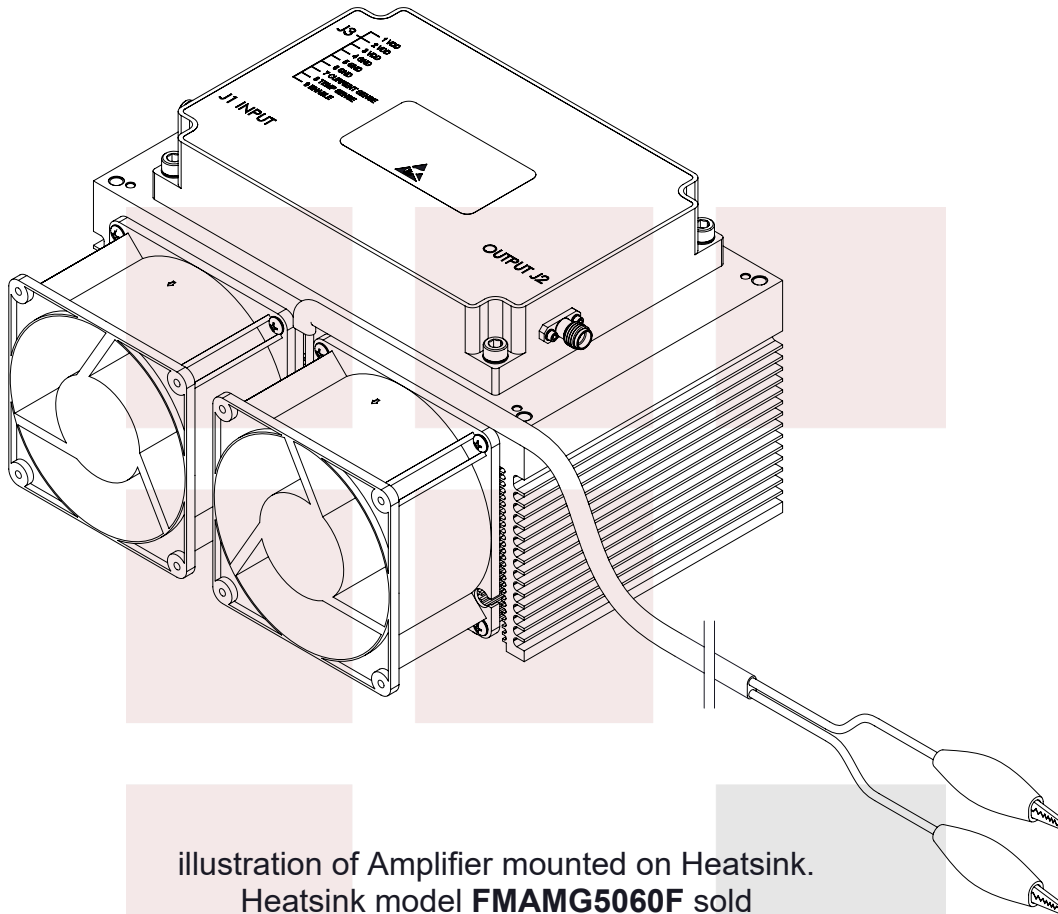
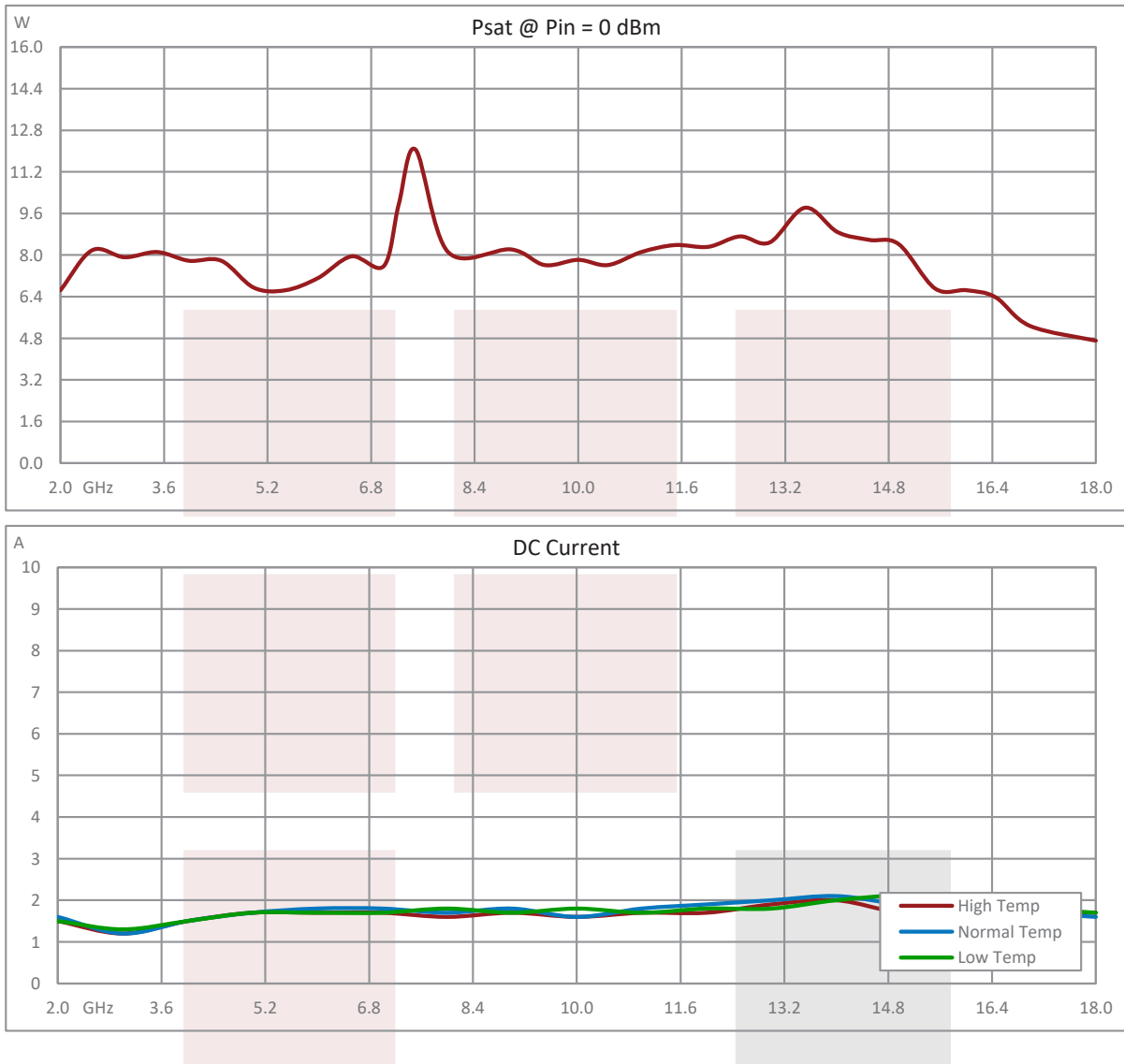
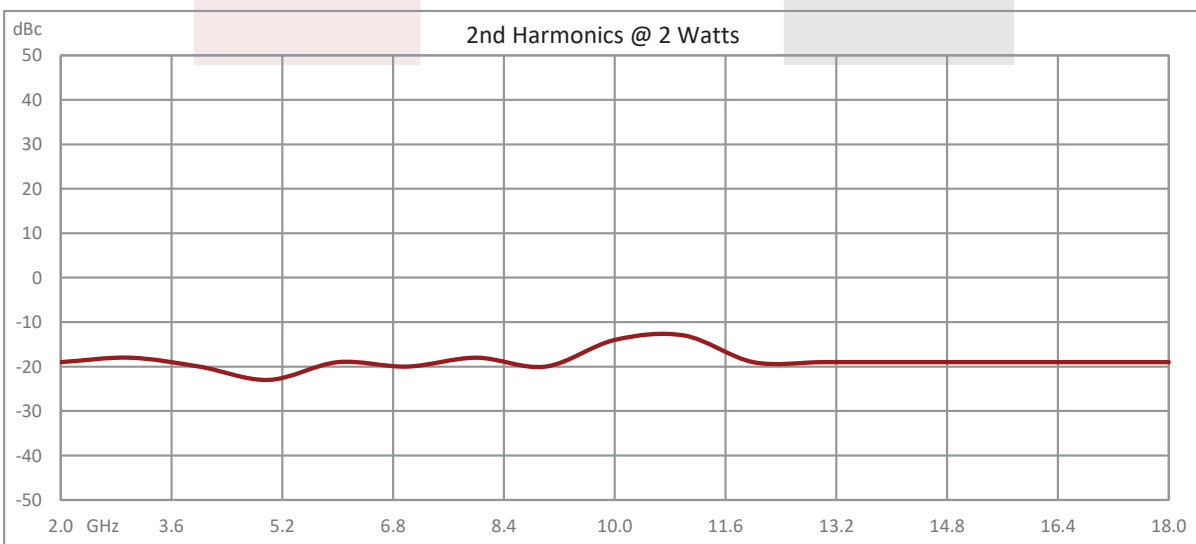
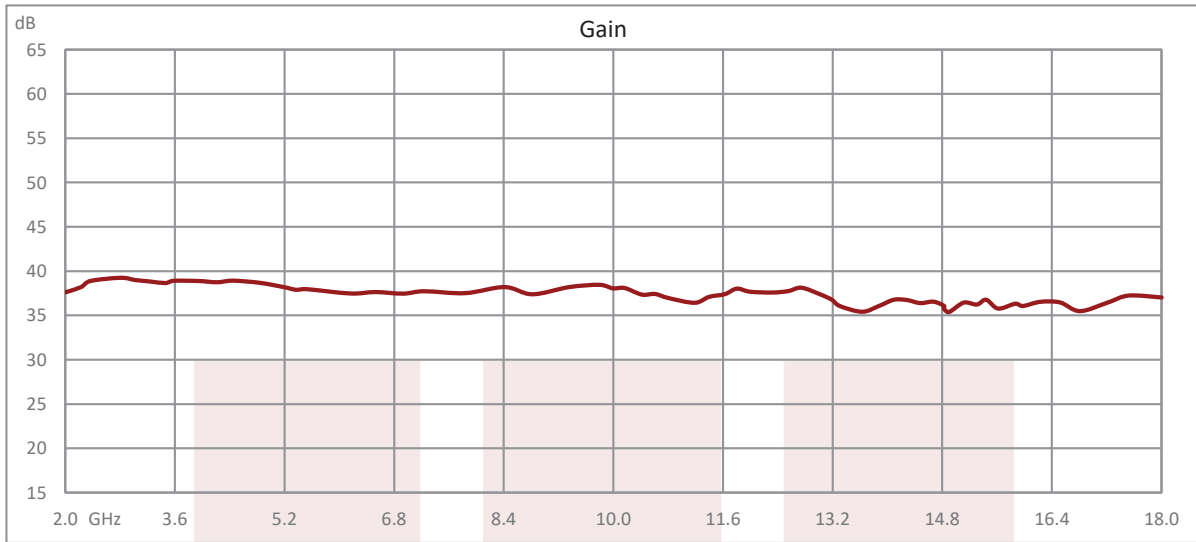


illustration of Amplifier mounted on Heatsink.
Heatsink model **FMAMG5060F** sold
separately.(Picture shown for Reference Only)

Typical Performance Data



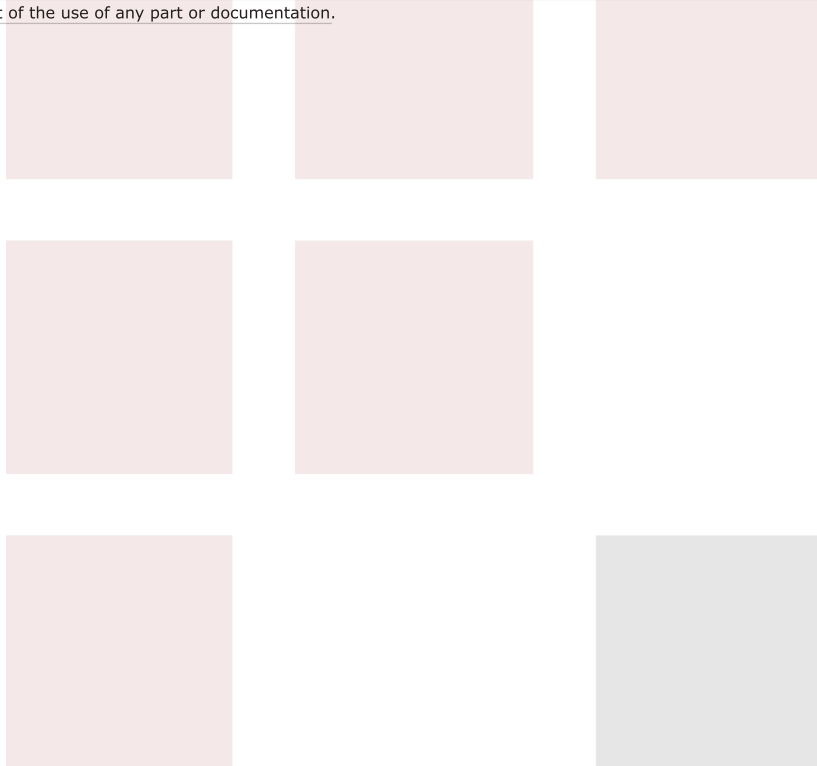


High Power GaN Amplifier at 5 Watt Psat Operating from 2 GHz to 18 GHz with SMA from Fairview Microwave is in-stock and available to ship same-day. All of our RF/microwave products are available off-the-shelf from our ISO 9001:2008 certified facilities in Lewisville, Texas. Fairview Microwave is RF on-demand.

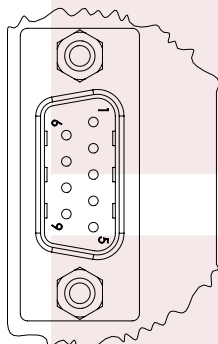
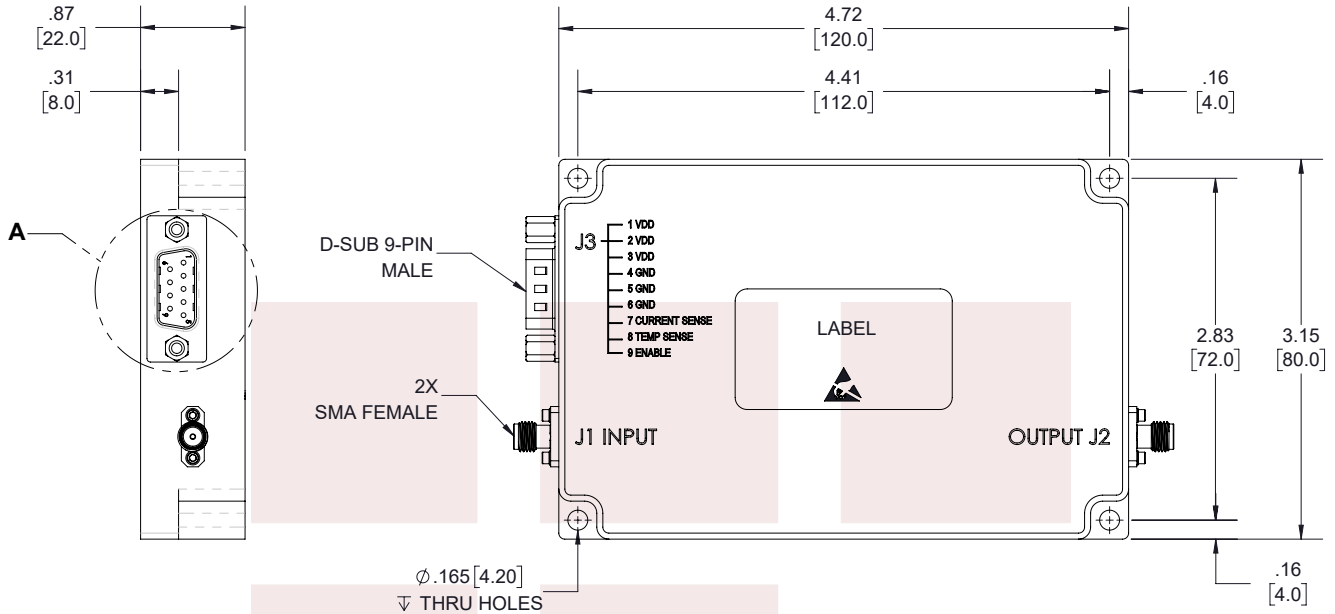
For additional information on this product, please click the following link: [High Power GaN Amplifier at 5 Watt Psat Operating from 2 GHz to 18 GHz with SMA FMAM5068](#)

URL: <https://www.fairviewmicrowave.com/high-power-amplifier-5watt-fmam5068-p.aspx>

The information contained in this document is accurate to the best of our knowledge and representative of the part described herein. It may be necessary to make modifications to the part and/or the documentation of the part, in order to implement improvements. Fairview Microwave reserves the right to make such changes as required. Unless otherwise stated, all specifications are nominal. Fairview Microwave does not make any representation or warranty regarding the suitability of the part described herein for any particular purpose, and Fairview Microwave does not assume any liability arising out of the use of any part or documentation.

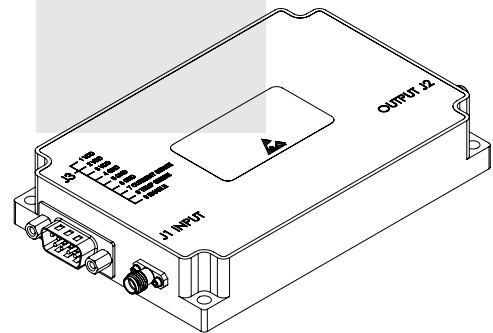


REVISIONS			
REV.	DESCRIPTION	DATE	APPROVED
B	PCR PE15A5068 FMAM5068 2022077	07/26/2022	TGALLA



DETAIL A

D-SUB 9-PIN, MALE		
PIN #	DESCRIPTION	SPECIFICATIONS
1,2,3	VDD	28 VDC
4,5,6	GND	Ground
7	CURRENT SENSE	Analog voltage relative to IDD @100mV per Ampere
8	TEMP SENSE	Analog voltage relative to Module's Temperature @10 mV/°C
9	ENABLE	Amplifier Enable: TTL Logic High (3.3V) (Internally Pulled-Low)



LABEL



NOTES:

- ADEQUATE HEATSINK REQUIRED.

THESE COMMODITIES, TECHNOLOGY OR SOFTWARE WERE EXPORTED FROM THE UNITED STATES IN ACCORDANCE WITH THE EXPORT ADMINISTRATION REGULATIONS. DIVERSION CONTRARY TO U.S. LAW PROHIBITED.

TITLE

High Power GaN Amplifier at 5 Watt Psat Operating from 2 GHz to 18 GHz with SMA

UNLESS OTHERWISE SPECIFIED LEADING DIMENSIONS ARE INCHES
DIMENSIONS IN [] ARE MILLIMETERS

TOLERANCES: CABLE LENGTH (L) TOLERANCES:

.X = ±.2 [5.08]	FRACTIONS	L ≤ 12 [305] = +1 [25] / -0
.XX = ±.02 [.51]	± 1/32	12 [305] < L ≤ 60 [1524] = +2 [51] / -0
.XXX = ±.005 [.13]	ANGLES ± 1°	60 [1524] < L ≤ 120 [3048] = +4 [102] / -0
		120 [3048] < L ≤ 300 [7620] = +6 [152] / -0
		300 [7620] < L = +5%L / -0

THIRD-ANGLE PROJECTION



THE INFORMATION AND DESIGN IN THIS DOCUMENT IS THE PROPERTY OF FAIRVIEW MICROWAVE CORPORATION. ALL RIGHTS RESERVED.

SHEET 1 OF 1

ALL DIMENSIONS SHOWN ARE FOR REFERENCE ONLY.

SCALE N/A

SIZE A	CAGE CODE 3FKR5	DRAWN BY KGLEBOVA	ITEM NO. FMAM5068	REV B
-----------	--------------------	----------------------	----------------------	----------

T-Rev.D